

PNP General Purpose Amplifier

This device is designed for use as a general purpose amplifier and switch requiring collector currents to 500 mA.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	40	V	
V _{CBO}	Collector-Base Voltage	40	V	
V _{EBO}	Emitter-Base Voltage	5.0	V	
lc	Collector Current - Continuous	600	mA	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

Symbol	Characteristic	Max		Units	
		2N4403	*MMBT4403		
PD	Total Device Dissipation	625	350	mW	
	Derate above 25°C	5.0	2.8	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W	

TA = 25°C unless otherwise noted

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

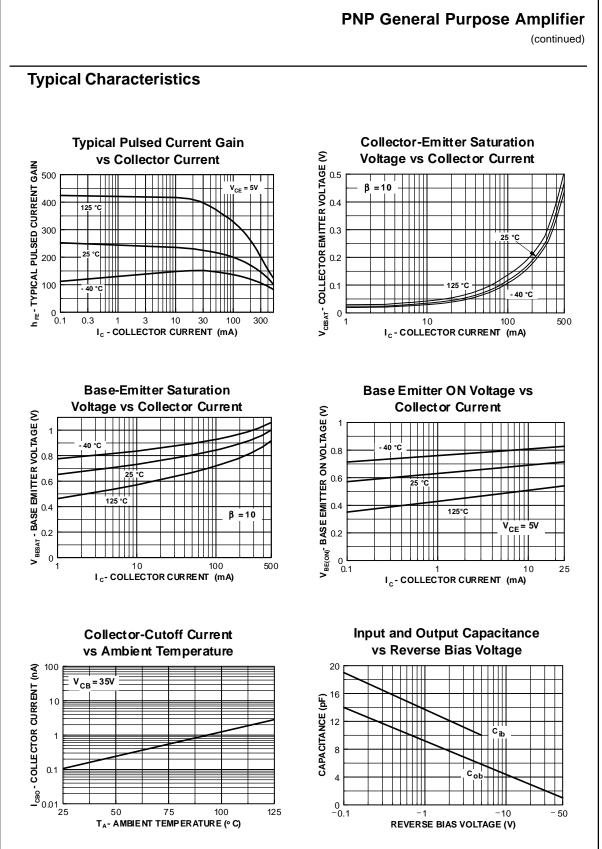
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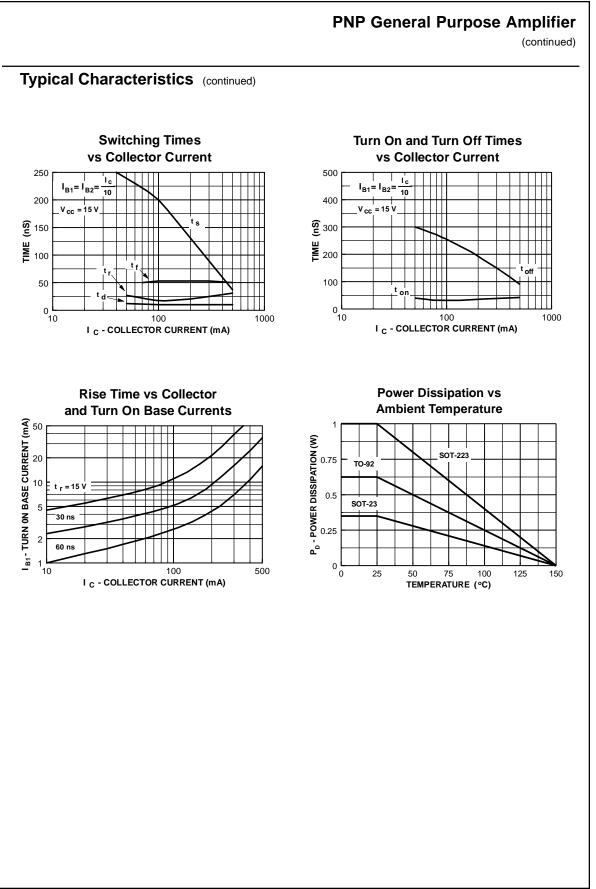
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Symbol	ical Characteristics TA: Parameter	= 25°C unless otherwise noted Test Conditions	Min	Max	Units
	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 0.1 \text{ mA}, I_{\rm E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 0.1 \text{ A}, I_{\rm C} = 0$	5.0		V
I _{BEX}	Base Cutoff Current	V _{CE} = 35 V, V _{EB} = 0.4 V		0.1	μA
ICEX	Collector Cutoff Current	V _{CE} = 35 V, V _{BE} = 0.4 V		0.1	μA
N/	Collector Emitter Schurstion	$I_{C} = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$ $I_{C} = 150 \text{ mA}, V_{CE} = 2.0 \text{ V}^{*}$ $I_{C} = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}^{*}$	100 100 20	300	M
				300	
V _{CE(sat)}	Collector-Emitter Saturation Voltage*	$I_{C} = 150 \text{ mA}, I_{B} = 15 \text{ mA}$ $I_{C} = 500 \text{ mA}, I_{B} = 50 \text{ mA}$		0.4 0.75	V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{C} = 150 \text{ mA}, I_{B} = 15 \text{ mA}^{*}$ $I_{C} = 500 \text{ mA}, I_{B} = 50 \text{ mA}$	0.75	0.95 1.3	V V
SMALL SI f _T C _{cb}	GNAL CHARACTERISTICS Current Gain - Bandwidth Product Collector-Base Capacitance	$I_{C} = 20 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 100 MHz $V_{CB} = 10 \text{ V}, I_{E} = 0,$	200	8.5	MHz
C _{eb}	Emitter-Base Capacitance	f = 140 kHz V _{BE} = 0.5 V, I _C = 0,		30	pF
h _{ie}	Input Impedance	f = 140 kHz $I_C = 1.0 \text{ mA}, V_{CE} = 10 \text{ V},$	1.5	15	' kΩ
		f = 1.0 kHz			
h _{re}	Voltage Feedback Ratio	$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ kHz}$	0.1	8.0	x 10 ⁻⁴
h _{fe}	Small-Signal Current Gain	$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ kHz}$	60	500	
	Output Admittance	$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V},$	1.0	100	μmhos

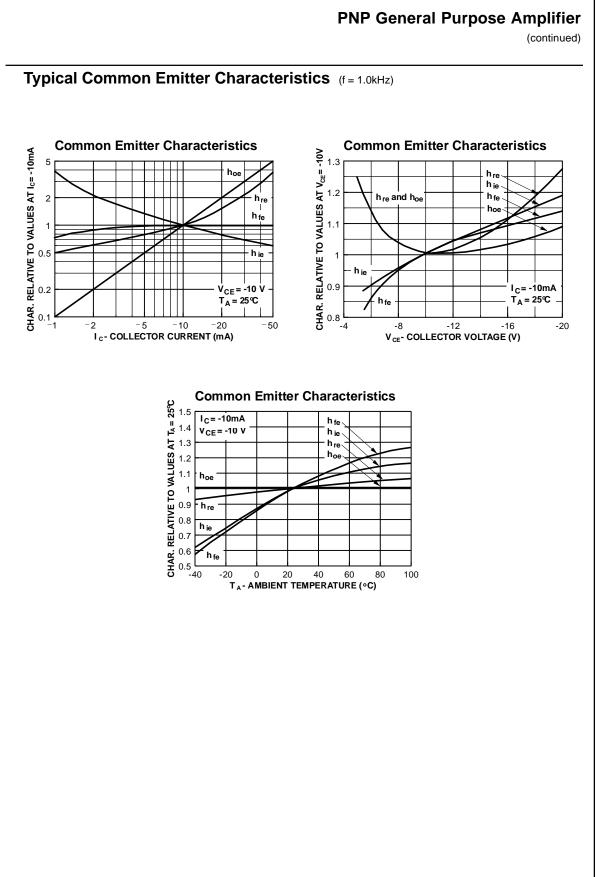
SWITCHING CHARACTERISTICS

t _d	Delay Time	$V_{CC} = 30 \text{ V}, I_C = 150 \text{ mA},$	15	ns
tr	Rise Time	I _{B1} = 15 mA	20	ns
ts	Storage Time	V _{CC} = 30 V, I _C = 150 mA	225	ns
t _f	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$	30	ns

*Pulse Test: Pulse Width \pm 300 ms, Duty Cycle \pm 2.0%







PNP General Purpose Amplifier (continued)

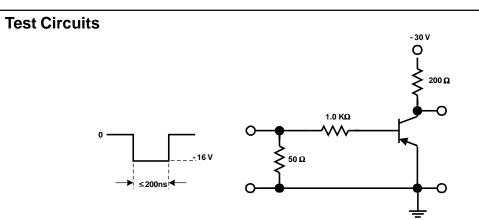


FIGURE 1: Saturated Turn-On Switching Time Test Circuit

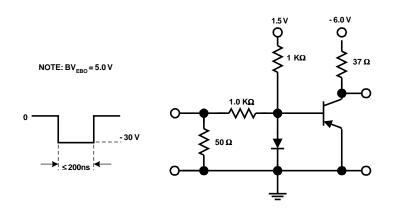


FIGURE 2: Saturated Turn-Off Switching Time Test Circuit

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